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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
09/579,402	05/25/2000	KEI-YU KO	11675.114.1	7953	
75	90 02/28/2002				
BRADLEY K DESANDRO WORKMAN NYDEGGER & SEELEY 1000 EAGLE GATE TOWER			EXAMINER		
			LEE, EUGENE		
60 EAST SOUT SALT LAKE C	TH TEMPLE ITY, UT 84111		ART UNIT	7953 EXAMINER EE, EUGENE PAPER NUMBER	
	,		2815		
			DATE MAILED: 02/28/2002		

Please find below and/or attached an Office communication concerning this application or proceeding.

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	. •	Application No.	Applicant(s)
	Office Action Survey	09/579,402	KO, KEI-YU
	Office Action Summary	Examiner	Art Unit
	The MALLING DATE - CALL	Eugene Lee	2815
Period f	The MAILING DATE of this communication app or Reply	ars on the cover sheet w	ith the correspondence address
- External control con	HORTENED STATUTORY PERIOD FOR REPL' MAILING DATE OF THIS COMMUNICATION. Persions of time may be available under the provisions of 37 CFR 1.13 of SIX (6) MONTHS from the mailing date of this communication. The period for reply specified above is less than thirty (30) days, a reply of period for reply is specified above, the maximum statutory period were to reply within the set or extended period for reply will, by statute, reply received by the Office later than three months after the mailing end patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a r within the statutory minimum of thin will apply and will expire SIX (6) MON	reply be timely filed by (30) days will be considered timely. ITHS from the mailing date of this communication.
1)⊠	Responsive to communication(s) filed on 25 M	fav 2000	
2a)⊠		s action is non-final.	
3)	Since this application is in condition for allowa		tore proposition as to the second to
	closed in accordance with the practice under t	Ex parte Quayle, 1935 C.	D. 11, 453 O.G. 213.
Dispositi	ion of Claims		
4) 🖂	Claim(s) 1-20 is/are pending in the application.		•
	4a) Of the above claim(s) is/are withdraw	n from consideration.	
5) 🗌	Claim(s) is/are allowed.		
6)🖂	Claim(s) 1-20 is/are rejected.		
7) 🗌	Claim(s) is/are objected to.		
8) 🗌	Claim(s) are subject to restriction and/or	election requirement.	
Applicati	on Papers		
9) 🔲 🗆	The specification is objected to by the Examiner.		
10)□ 7	Fhe drawing(s) filed on is/are: a)□ accept	ed or b) objected to by th	e Examiner.
	Applicant may not request that any objection to the	drawing(s) be held in abevar	nce. See 37 CFR 1 85(a)
11) 🔲 T	he proposed drawing correction filed on	is: a)□ approved b)□ dis	sapproved by the Examiner.
	If approved, corrected drawings are required in reply	y to this Office action.	•
12) 🔲 T	he oath or declaration is objected to by the Exa	miner.	
Priority u	nder 35 U.S.C. §§ 119 and 120		
13) 🗌 🛚	Acknowledgment is made of a claim for foreign	priority under 35 U.S.C. §	119(a)-(d) or (f).
a)[☐ All b)☐ Some * c)☐ None of:		
•	1. Certified copies of the priority documents.	have been received.	
2	2. Certified copies of the priority documents	have been received in Ap	plication No
	B. Copies of the certified copies of the priority application from the International Bure the attached detailed Office action for a list of	y documents have been ro au (PCT Rule 17 2(a))	eceived in this National Stage
	cknowledgment is made of a claim for domestic		
a)	☐ The translation of the foreign language provi	sional annication has been	ा । ब(ब) (to a provisional application).
15)⊠ Áo	cknowledgment is made of a claim for domestic	priority under 35 U.S.C. §	श 120 and/or 121.
tachment(s			V
■ Notice	of References Cited (PTO-892) of Draftsperson's Patent Drawing Review (PTO-948) ttion Disclosure Statement(s) (PTO-1449) Paper No(s)	5) Notice of Info	mmary (PTO-413) Paper No(s) ormal Patent Application (PTO-152)
Patent and Trad			

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DETAILED ACTION

Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- Claims 1 thru 3, 5 thru 8, 11 thru 13, and 15 thru 18 are rejected under 35 U.S.C. 103(a) 2. as being unpatentable over Lee et al. '703 in view of Havemann '894. Lee discloses (see, for example, FIG. 22) a semiconductor device comprising a silicon substrate (semiconductor material) 3, dielectric layer (gate oxide layer) 4, polysilicon layer (gate layer) 10, metal silicide layer (layer of refractory metal silicide) 15, oxide cap 16, spacer 35, tungsten fill (contact plug) 90, BPSG oxide (layer of doped silicon dioxide) 75, and TiN 85. In column 7, lines 18-29, Lee discloses the tungsten fill 90 and the TiN 85 forming a core 95 that contacts the substrate contact area 82. In column 6, lines 59-*, Lee discloses TiN as diffusion barrier metal. Lee does not disclose a cap made of undoped silicon dioxide. However, Havemann teaches (see, for example, column 2, line 66) that many different insulative materials (such as silicon dioxide) may be used in a cap of a gate stack structure. It would have been obvious to one of ordinary skill in the art at the time of invention to use undoped silicon dioxide in the cap of Lee, since it has been held to be within the general skill of a worker in the art to select a known material on the basis of its suitability (strong insulative properties) for the intended use (for a spacer) as a matter of obvious design choice. In re Leshin, 125 USPQ 416.

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- a. Regarding claim 2, Lee does not disclose the nonconductive material comprising silicon nitride. However, Havemann teaches (see, for example, column 2, line 66) that many different insulative materials (such as silicon dioxide) may be used in the spacers of a gate stack structure. Therefore, it would have been obvious to one of ordinary skill in the art at the time of invention to use silicon nitride, since it has been held to be within the general skill of a worker in the art to select a known material on the basis of its suitability for the intended use as a matter of obvious design choice. In re Leshin, 125 USPQ 416.
- b. Regarding claims 3 and 7, see, for example, column 5, line 53 of Lee
- c. Regarding claim 5, see, for example, column 5, line 42 of Lee.
- d. Regarding claim 6, see, for example, column 6, line 40 of Lee.
- 3. Claims 4, 9, 10, 14, 19 and 20 are rejected under 35 U.S.C. 103(a) as being unpatentable over Lee et al. '703 in view of Havemann '894 as applied to claims 1 thru 3, 5 thru 8, 11 thru 13, and 15 thru 18 above, and further in view of Ahmad et al. '176. Lee in view of Havemann does not disclose the semiconductor material being made of monocrystalline silicon. However, Ahmad discloses (see, for example, column 3, lines 39-43) that DRAM semiconductor devices are typically formed on monocrystalline silicon. Therefore it would have been obvious to one of ordinary skill in the art at the time of invention to use monocrystalline silicon in Lee in view of Havemann in order to have a substrate suitable for a semiconductor device with minimum crystal defect and a smooth surface.

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Response to Arguments

4. Applicant's arguments with respect to claims 1-20 have been considered but are moot in view of the new ground(s) of rejection.

Conclusion

5. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

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INFORMATION ON HOW TO CONTACT THE USPTO

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Eugene Lee whose telephone number is 703-305-5695. The examiner can normally be reached on M-F 8-5.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Eddie C. Lee can be reached on 703-308-1690. The fax phone numbers for the organization where this application or proceeding is assigned are 703-308-7722 for regular communications and 703-308-7722 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0956.

Eugene Lee February 24, 2002

EDDIE LEE

SUPERVISORY PATENT EXAMINER TECHNOLOGY CENTER 2800